

BFG 235 E6327 Information



For Reference Only

Part Number BFG 235 E6327

Manufacturer Infineon Technologies

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - RF **Description** TRANSISTOR RF NPN 15V SOT-223

Package TO-261-4, TO-261AA

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









BFG 235 E6327 Specifications

Manufacturer Part Number	BFG 235 E6327
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - RF
Package	TO-261-4, TO-261AA
Series	-
Transistor Type	NPN
Voltage - Collector Emitter Breakdown (Max)	15V
Frequency - Transition	5.5GHz
Noise Figure (dB Typ @ f)	1.7dB @ 900MHz
Gain	12.5dB
Power - Max	2W
DC Current Gain (hFE) (Min) @ Ic, Vce	75 @ 200mA, 8V
Current - Collector (Ic) (Max)	300mA
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Package / Case	TO-261-4, TO-261AA
Supplier Device Package	PG-SOT223-4
	Report errors?

BFG 235 E6327 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

BFG 235 E6327 Payment Methods



















BFG 235 E6327 Shipping Methods













If you have any question about BFG 235 E6327, please do not hesitate to contact us!

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